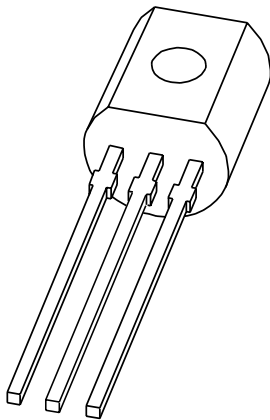


# DATA SHEET



## **JC327** PNP general purpose transistor

Product specification  
Supersedes data of 1999 Apr 27

2004 Dec 08

PNP general purpose transistor

JC327

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 45 V).

APPLICATIONS

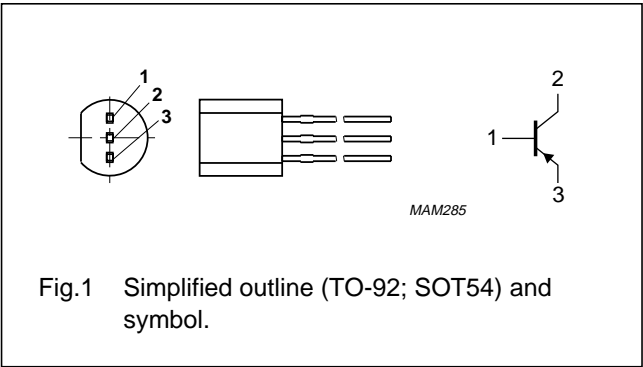
- General purpose switching and amplification, e.g. driver and output stages of audio amplifiers.

DESCRIPTION

PNP transistor in a TO-92; SOT54 plastic package.  
NPN complement: JC337.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
JC327-25	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54

## PNP general purpose transistor

JC327

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–50	V
$V_{CEO}$	collector-emitter voltage	open base; $I_C = -10$ mA	–	–45	V
$V_{EBO}$	emitter-base voltage	open collector	–	–5	V
$I_C$	collector current (DC)		–	–500	mA
$I_{CM}$	peak collector current		–	–1	A
$I_{BM}$	peak base current		–	–200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C; note 1	–	625	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	ambient temperature		–65	+150	°C

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	200	K/W

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## CHARACTERISTICS

 $T_{amb} = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -20$ V; $I_E = 0$ A	–	–	–100	nA
		$V_{CB} = -20$ V; $I_E = 0$ A; $T_j = 150$ °C	–	–	–5	μA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = -5$ V; $I_C = 0$ A	–	–	–100	nA
$h_{FE}$	DC current gain	$V_{CE} = -1$ V				
		$I_C = -100$ mA	160	–	400	
		$I_C = -500$ mA	40	–	–	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -500$ mA; $I_B = -50$ mA	–	–	–700	mV
$V_{BE}$	base-emitter voltage	$V_{CE} = -1$ V; $I_C = -500$ mA; note 1	–	–	–1.2	V
$C_c$	collector capacitance	$V_{CB} = -10$ V; $I_E = i_e = 0$ A; $f = 1$ MHz	–	8	–	pF
$f_T$	transition frequency	$V_{CE} = -5$ V; $I_C = -10$ mA; $f = 100$ MHz	80	–	–	MHz

## Note

1.  $V_{BE}$  decreases by about –2 mV/K with increasing temperature.

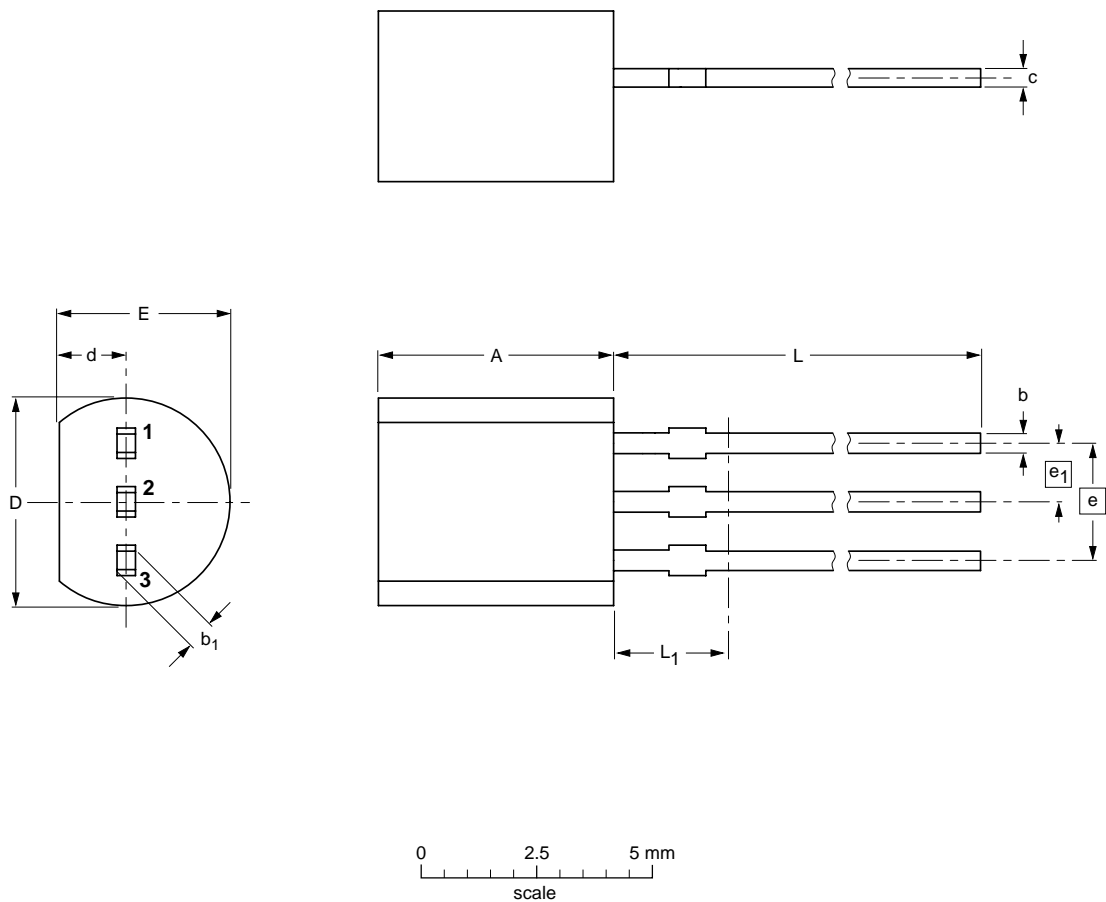
PNP general purpose transistor

JC327

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT54		TO-92	SC-43A			04-06-28 04-11-16

## PNP general purpose transistor

JC327

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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